TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MH138FK

3-to-8 Line Decoder

The TC7MH138FK is an advanced high speed CMOS 3-to-8 decoder fabricated with silicon gate C^2 MOS technology.

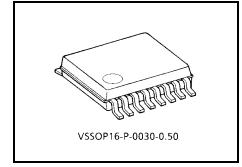
It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 binary select inputs (A, B and C) determine which one of the outputs $(\overline{Y}0 \cdot \overline{Y}7)$ will go low.

When enable input G1 is held low or either $\overline{G}2A$ or $\overline{G}2B$ is held high, decoding function is inhibited and all outputs go high.

G1, G2A, and G2B inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage.



Weight: 0.02 g (typ.)

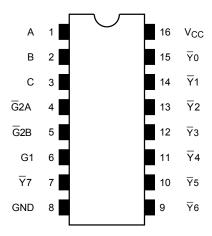
This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

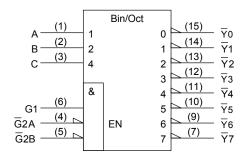
- High speed: $t_{pd} = 5.7 \text{ ns (typ.) (VCC} = 5 \text{ V)}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max) (Ta} = 25 ^{\circ}\text{C)}$
- High noise immunity: VNIH = VNIL = 28% VCC (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: $V_{CC \text{ (opr)}} = 2 \sim 5.5 \text{ V}$
- Pin and function compatible with 74ALS138

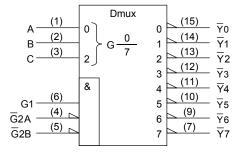
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Pin Assignment (top view)



IEC Logic Symbol





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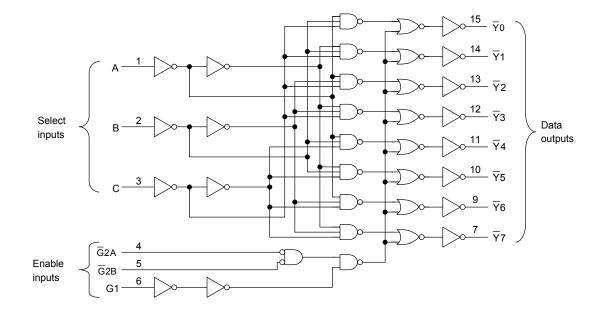
Truth Table

TOSHIBA

Inputs					Outputs										
	Enable		Select			_ Y0	<u></u>		_ Y3	_ Y4	_ Y5	<u>-</u> Y6	_ Y7	Selected Output	
G1	G ₂ A	G ₂ B	С	В	Α	10	10 11	12	13	14	13	10	Υ /		
L	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None	
Х	Н	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None	
Х	Х	Н	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None	
Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	\ \{\foat}0	
Н	L	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	₹1	
Н	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н	₹2	
Н	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н	\overline{Y} 3	
Н	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н	Y 4	
Н	L	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	Y 5	
Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Y 6	
Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L	Y 7	

X: Don't care

Logic Diagram



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5~7.0	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	Vout	-0.5~V _{CC} + 0.5	V
Input diode current	lικ	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	P _D	180	mW
Storage temperature	T _{stg}	-65~150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0~5.5	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V _{OUT}	0~V _{CC}	V	
Operating temperature	T _{opr}	− 40~85	°C	
Input rise and fall time	dt/dv	$0\sim100~(V_{CC}=3.3\pm0.3~V)$	ns/V	
input rise and fail tille	didv	0~20 (V _{CC} = 5 ± 0.5 V)		

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition				Га = 25°C)	Ta = -40~85°C		Unit	
Characte	51151105	Syllibol	rest Condition		V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic	
			_		2.0	1.50	_	_	1.50	_		
Input voltage	High level	V _{IH}			3.0~5.5	V _{CC} × 0.7	_	_	V _{CC} × 0.7	Unit		
input voitage					2.0	I	_	0.50	_	0.50	V	
	Low level	V _{IL}	_		3.0~5.5			V _{CC} × 0.3	_	$\begin{array}{c} V_{CC} \\ \times \ 0.3 \end{array}$		
		V _{OH}	V _{IN} = V _{IH}	I _{OH} = -50 μA	2.0	1.9	2.0	_	1.9		-	
					3.0	2.9	3.0	_	2.9			
	High level				4.5	4.4	4.5	_	4.4			
$ \text{Input voltage} \begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	_	2.48										
Output voltage				$I_{OH} = -8 \text{ mA}$	4.5	3.94		_	3.80		V	
Output Voltage					2.0		0	0.1		0.1	v	
		$V_{OH} = V_{IH} = V$	0.1									
	Low level		or V _{IL}		4.5	_	0	0.1	_	0.1]	
				$I_{OL} = 4 \text{ mA}$	3.0		_	0.36	_	0.44		
				I _{OL} = 8 mA	4.5	_	_	0.36	_	0.44		
Input leakage current		I _{IN}	V _{IN} = 5.5 V or GND		0~5.5			±0.1	_	±1.0	μA	
Quiescent supply current		Icc	$V_{IN} = V_{CC}$	V _{IN} = V _{CC} or GND		_	_	4.0	_	40.0	μΑ	



AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

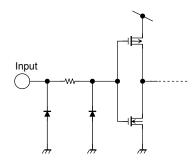
Characteristics	Symbol	Test Condition			-	Ta = 25°C)	Ta = −40~		Unit
Characteristics	Symbol	rest Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Unit
			3.3 ± 0.3	15	_	8.2	11.4	1.0	13.5	ns
Propagation delay time	t _{pLH}		J.J ± 0.3	50	_	10.0	15.8	1.0	18.0	
(A, B, C- \overline{Y})	t _{pHL}	_	50+05	15	_	5.7	8.1	1.0	9.5	115
			5.0 ± 0.5	50		7.2	10.1	1.0	11.5	
	t _{pLH}	_	3.3 ± 0.3	15		8.1	12.8	1.0	15.0	ns
Propagation delay time			3.3 ± 0.3	50		10.6	16.3	1.0	18.5	
(G1- \overline{Y})	t _{pHL}		5.0 ± 0.5	15		5.6	8.1	1.0	9.5	
			5.0 ± 0.5	50		7.1	10.1	1.0	11.5	
	^t pLH ^t pHL	_	3.3 ± 0.3	15		8.2	11.4	1.0	13.5	ns
Propagation delay time				50		10.7	14.9	1.0	17.0	
(G2 - Y)			5.0 ± 0.5	15		5.8	8.1	1.0	9.5	
				50	_	7.3	10.1	1.0	11.5	
Input capacitance	C _{IN}	-	_		_	4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note)		34	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

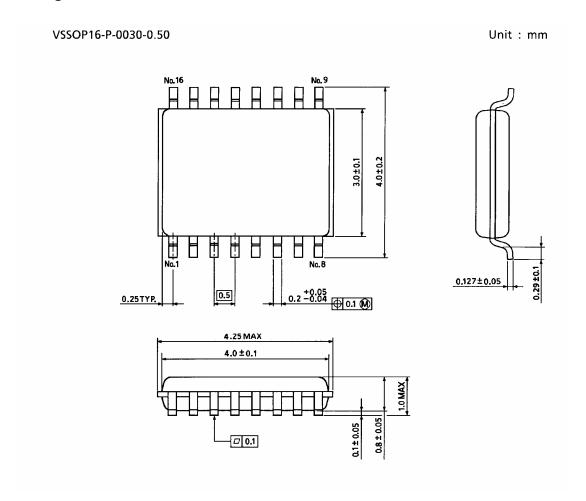
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Input Equivalent Circuit



Package Dimensions



Weight: 0.02 g (typ.)

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